









ULN2002A, ULN2003A, ULN2003AI ULQ2003A, ULN2004A, ULQ2004A

SLRS027Q - DECEMBER 1976 - REVISED JULY 2022

ULN200x, ULQ200x High-Voltage, High-Current Darlington Transistor Arrays

1 Features

- 500-mA-Rated Collector Current (Single Output)
- High-Voltage Outputs: 50 V
- **Output Clamp Diodes**
- Inputs Compatible With Various Types of Logic
- **Relay-Driver Applications**

2 Applications

- Relay Drivers
- Stepper and DC Brushed Motor Drivers
- Lamp Drivers
- Display Drivers (LED and Gas Discharge)
- Line Drivers
- Logic Buffers

3 Description

The ULx200xA devices are high-voltage, high-current Darlington transistor arrays. Each consists of seven NPN Darlington pairs that feature high-voltage outputs with common-cathode clamp diodes for switching inductive loads.

The collector-current rating of a single Darlington pair is 500 mA. The Darlington pairs can be paralleled for higher current capability. Applications include relay drivers, hammer drivers, lamp drivers, display drivers (LED and gas discharge), line drivers, and logic buffers. For 100-V (otherwise interchangeable) versions of the ULx2003A devices, see the SLRS023 data sheet for the SN75468 and SN75469 devices.

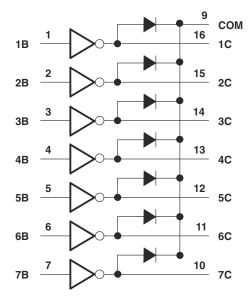
The ULN2002A device is designed specifically for use with 14-V to 25-V PMOS devices. Each input of this device has a Zener diode and resistor in series to control the input current to a safe limit. The ULx2003A devices have a 2.7-kΩ series base resistor for each Darlington pair for operation directly with TTL or 5-V CMOS devices.

The ULx2004A devices have a 10.5-kΩ series base resistor to allow operation directly from CMOS devices that use supply voltages of 6 V to 15 V. The required input current of the ULx2004A device is below that of the ULx2003A devices, and the required voltage is less than that required by the ULN2002A device.

Device Information⁽¹⁾

| PART NUMBER | PACKAGE | BODY SIZE (NOM) |
|-------------|------------|--------------------|
| ULx200xD | SOIC (16) | 9.90 mm × 3.91 mm |
| ULx200xN | PDIP (16) | 19.30 mm × 6.35 mm |
| ULN200xNS | SOP (16) | 10.30 mm × 5.30 mm |
| ULN200xPW | TSSOP (16) | 5.00 mm × 4.40 mm |

For all available packages, see the orderable addendum at (1) the end of the data sheet.



Simplified Block Diagram



Table of Contents

| 1 Features | 1 | 7 Parameter Measurement Information | |
|--|--|--|--|
| 2 Applications | 1 | 8 Detailed Description | |
| 3 Description | | 8.1 Overview | |
| 4 Revision History | | 8.2 Functional Block Diagrams | |
| 5 Pin Configuration and Functions | | 8.3 Feature Description | |
| 6 Specifications | 4 | 8.4 Device Functional Modes | 13 |
| | | 9 Application and Implementation | 14 |
| | | 9.1 Application Information | 14 |
| 6.3 Recommended Operating Conditions | 4 | 9.2 Typical Application | 14 |
| 6.4 Thermal Information | 4 | | |
| 6.5 Electrical Characteristics: ULN2002A | 5 | 10 Power Supply Recommendations | 18 |
| 6.6 Electrical Characteristics: ULN2003A and | | 11 Layout | 18 |
| ULN2004A | 5 | 11.1 Layout Guidelines | 18 |
| 6.7 Electrical Characteristics: ULN2003AI | 6 | 11.2 Layout Example | 18 |
| 6.8 Electrical Characteristics: ULN2003AI | 6 | 12 Device and Documentation Support | 19 |
| 6.9 Electrical Characteristics: ULQ2003A and | | | |
| ULQ2004A | 7 | | |
| | | | |
| | 7 | | |
| | | | |
| | | | |
| | | | |
| | 8 | | |
| | | | 19 |
| | | | Page |
| NOTE: Page numbers for previous revisions may Changes from Revision P (August 2019) to Re | vision | Q (July 2022) | |
| NOTE: Page numbers for previous revisions may Changes from Revision P (August 2019) to Re Updated the numbering format for tables, figure Changes from Revision O (January 2016) to Re | evision res, and Revisio | Q (July 2022) d cross-references throughout the document n P (August 2019) | Page |
| NOTE: Page numbers for previous revisions may Changes from Revision P (August 2019) to Re Updated the numbering format for tables, figure Changes from Revision O (January 2016) to Re Changed ULN200xA Minimum Temperature Re | acifications. 4 8.4 Device Functional Modes. 1.1 Absolute Maximum Ratings 4 9 Application and Implementation. 1.1 ESD Ratings. 4 9.1 Application Information. 1.1 Recommended Operating Conditions. 4 9.2 Typical Application. 1.1 Electrical Characteristics: ULN2002A. 5 10 Power Supply Recommendations. 1.1 Electrical Characteristics: ULN2003A and 11.2 Layout Guidelines. 1.1 Layout. 1.1 Layou | Page | |
| NOTE: Page numbers for previous revisions may Changes from Revision P (August 2019) to Re Updated the numbering format for tables, figure Changes from Revision O (January 2016) to Re Changed ULN200xA Minimum Temperature Re Changes from Revision N (June 2015) to Revision Revision N (February 2013) to Revision Revision M (February 2013) to Revision M (February 2013) | evision res, and Revision Rating fi sion O | Q (July 2022) d cross-references throughout the document n P (August 2019) rom –20 C to –40 C in the Section 6.1 table (January 2016) on N (June 2015) | Page Page |
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5 Pin Configuration and Functions

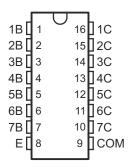


Figure 5-1. D, N, NS, and PW Package 16-Pin SOIC, PDIP, SO, and TSSOP Top View

Table 5-1. Pin Functions

| F | PIN | I/O ⁽¹⁾ | DESCRIPTION | | | | |
|------|-----|--------------------|---|--|--|--|--|
| NAME | NO. | 1/0(1) | DESCRIPTION | | | | |
| 1B | 1 | | | | | | |
| 2B | 2 | | | | | | |
| 3B | 3 | | | | | | |
| 4B | 4 | ı | nannel 1 through 7 Darlington base input | | | | |
| 5B | 5 | | | | | | |
| 6B | 6 | | | | | | |
| 7B | 7 | | | | | | |
| 1C | 16 | | | | | | |
| 2C | 15 | | | | | | |
| 3C | 14 | | | | | | |
| 4C | 13 | 0 | Channel 1 through 7 Darlington collector output | | | | |
| 5C | 12 | | | | | | |
| 6C | 11 | | | | | | |
| 7C | 10 | | | | | | |
| СОМ | 9 | _ | Common cathode node for flyback diodes (required for inductive loads) | | | | |
| E | 8 | _ | Common emitter shared by all channels (typically tied to ground) | | | | |

(1) I = Input, O = Output

6 Specifications

6.1 Absolute Maximum Ratings

at 25°C free-air temperature (unless otherwise noted)(1)

| | | | MIN | MAX | UNIT |
|------------------|--|-----------|-----|------|------|
| V _{CC} | Collector-emitter voltage | | | 50 | V |
| | Clamp diode reverse voltage ⁽²⁾ | | | 50 | V |
| VI | Input voltage ⁽²⁾ | | | 30 | V |
| | Peak collector current, See Figure 6-4 and Figure 6-5 | | | 500 | mA |
| I _{OK} | Output clamp current | | | 500 | mA |
| | Total emitter-terminal current | | | -2.5 | Α |
| | ULN | | -40 | 70 | |
| _ | Operating free air temperature range | ULN200xAI | -40 | 105 | °C |
| I _A | Operating free-air temperature range | ULQ200xA | -40 | 85 | |
| | | ULQ200xAT | -40 | 105 | |
| TJ | Operating virtual junction temperature | • | | 150 | °C |
| | Lead temperature for 1.6 mm (1/16 inch) from case for 10 seconds | | | 260 | °C |
| T _{stg} | Storage temperature | | -65 | 150 | °C |

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 ESD Ratings

| | | | VALUE | UNIT |
|--------|---------------|--|-------|------|
| V | Electrostatic | Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾ | ±2000 | V |
| V(ESD) | discharge | Charged device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾ | ±500 | V |

⁽¹⁾ JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

| | | MIN | MAX | UNIT |
|-----------------|---|-----|-----|------|
| V _{CC} | Collector-emitter voltage (non-V devices) | 0 | 50 | V |
| T _J | Junction temperature | -40 | 125 | °C |

6.4 Thermal Information

| | | | ULx200x | | | | | |
|-------------------------------|--|-------------|-------------|------------|---------------|------|--|--|
| THERMAL METRIC ⁽¹⁾ | | D (SOIC) | N (PDIP) | NS (SO) | PW (TSSOP) | UNIT | | |
| | | 16 PINS | 16 PINS | 16 PINS | 16 PINS | | | |
| R _{0JA} | Junction-to-ambient thermal resistance | 73 | 67 | 64 | 108 | °C/W | | |
| R _{0JC(top)} | Junction-to-case (top) thermal resistance | 36 | 54 | n/a | 33.6 | °C/W | | |
| $R_{\theta JB}$ | Junction-to-board thermal resistance | n/a | n/a | n/a | 51.9 | °C/W | | |
| Ψ_{JT} | Junction-to-top characterization parameter | n/a | n/a | n/a | 2.1 | °C/W | | |
| ΨЈВ | Junction-to-board characterization parameter | n/a | n/a | n/a | 51.4 | °C/W | | |

For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report, SPRA953.

⁽²⁾ All voltage values are with respect to the emitter/substrate terminal E, unless otherwise noted.

⁽²⁾ JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



6.5 Electrical Characteristics: ULN2002A

 $T_A = 25^{\circ}C$

| | PARAMETER | TEST FIGURE | TEST C | ONDITIONS | UL | N2002A | | UNIT |
|--|---|-------------|---|-------------------------|---------------------|--------|--------------|------|
| | PARAMETER | 1EST FIGURE | IESIC | CNDITIONS | MIN | TYP | MAX | UNII |
| V _{I(on)} | ON-state input voltage | Figure 7-6 | V _{CE} = 2 V, | I _C = 300 mA | | | 13 | V |
| V _{OH} | High-level output voltage after switching | Figure 7-10 | V _S = 50 V, I _O = | = 300 mA | V _S - 20 | | | mV |
| | | | I _I = 250 μA, | I _C = 100 mA | | 0.9 | 1.1 | |
| V _{CE(sat)} | Collector-emitter saturation voltage | Figure 7-4 | I _I = 350 μA, | I _C = 200 mA | | 1 | 1.3 V 1.6 | V |
| | voltago | | I _I = 500 μA, | I _C = 350 mA | | 1.2 | 1.6 | |
| V _F | Clamp forward voltage | Figure 7-7 | I _F = 350 mA | | | 1.7 | 2 | V |
| | | Figure 7-1 | V _{CE} = 50 V, | I _I = 0 | | | 50 | |
| I _{CEX} | Collector cutoff current | Figure 7.0 | V _{CE} = 50 V, | I ₁ = 0 | | | 100 | μΑ |
| V _{CE(sat)} V _F I _{CEX} I _{I(off)} | | Figure 7-2 | T _A = 70°C | V _I = 6 V | | | 500 | |
| I _{I(off)} | OFF-state input current | Figure 7-2 | V _{CE} = 50 V, | I _C = 500 μA | 50 | 65 | | μA |
| II | Input current | Figure 7-3 | V _I = 17 V | | | 0.82 | 1.25 | mA |
| | Clamp reverse surrent | Figure 7.6 | V _R = 50 V | T _A = 70°C | | | 100 | |
| I _R | Clamp reverse current | Figure 7-6 | V _R = 50 V | | | | 50 | μA |
| C _i | Input capacitance | | V _I = 0, | f = 1 MHz | | | 25 | pF |

6.6 Electrical Characteristics: ULN2003A and ULN2004A

 $T_A = 25^{\circ}C$

| | PARAMETER | TEST | TEST CO | ONDITIONS | ULN | 12003A | | ULN | 12004A | | UNIT |
|---------------------|---|-------------|---|-------------------------|---------------------|--------|------|--------------------|--------|------|------|
| | PARAMETER | FIGURE | FIGURE TEST CONDIT | | MIN | TYP | MAX | MIN | TYP | MAX | UNII |
| | | | | I _C = 125 mA | | | | | | 5 | |
| | | | | I _C = 200 mA | | | 2.4 | | | 6 | |
| ., | ON-state input | Figure 7.0 | ., | I _C = 250 mA | | | 2.7 | | | | ., |
| $V_{I(on)}$ | voltage | Figure 7-6 | V _{CE} = 2 V | I _C = 275 mA | | | | | | 7 | V |
| | | | | I _C = 300 mA | | | 3 | | | | |
| | | | | I _C = 350 mA | | | | | | 8 | |
| V _{OH} | High-level output voltage after switching | Figure 7-10 | V _S = 50 V, I _O | = 300 mA | V _S - 20 | | | V _S -20 | | | mV |
| | Collector-emitter saturation voltage | | I _I = 250 μA, | I _C = 100 mA | | 0.9 | 1.1 | | 0.9 | 1.1 | |
| Va=(| | Figure 7-5 | I _I = 350 μA, | I _C = 200 mA | | 1 | 1.3 | | 1 | 1.3 | V |
| | | Voltago | I _I = 500 μA, | I _C = 350 mA | | 1.2 | 1.6 | | 1.2 | 1.6 | |
| | | Figure 7-1 | V _{CE} = 50 V, | I ₁ = 0 | | | 50 | | | 50 | - |
| I_{CEX} | Collector cutoff current | Figure 7-2 | V _{CE} = 50 V, | I ₁ = 0 | | | 100 | | | 100 | μΑ |
| | Garrone | Figure 7-2 | T _A = 70°C | V _I = 6 V | | | | | | 500 | |
| V _F | Clamp forward voltage | Figure 7-8 | I _F = 350 mA | | | 1.7 | 2 | | 1.7 | 2 | ٧ |
| I _{I(off)} | Off-state input current | Figure 7-3 | V _{CE} = 50 V, T _A = 70°C, | I _C = 500 μA | 50 | 65 | | 50 | 65 | | μA |
| | | | V _I = 3.85 V | | | 0.93 | 1.35 | | | | |
| I | Input current | Figure 7-4 | V _I = 5 V | | | | | | 0.35 | 0.5 | mA |
| | | | V _I = 12 V | | | | | | 1 | 1.45 | |
| | Clamp reverse | Figure 7.7 | V _R = 50 V | | | , | 50 | | | 50 | |
| I _R | current | Figure 7-7 | V _R = 50 V | T _A = 70°C | | | 100 | | | 100 | μA |



6.6 Electrical Characteristics: ULN2003A and ULN2004A (continued)

 $T_A = 25^{\circ}C$

| | PARAMETER | PARAMETER TEST TEST CONDITIONS | | | | ULN2003A | | | ULN2004A | | |
|----|-------------------|--------------------------------|---------------------|-----------------|--|----------|-----|-----|----------|-----|------|
| | FANAMETER | FIGURE | 120 | TEST CONDITIONS | | TYP | MAX | MIN | TYP | MAX | UNIT |
| Ci | Input capacitance | | V _I = 0, | f = 1 MHz | | 15 | 25 | | 15 | 25 | pF |

6.7 Electrical Characteristics: ULN2003AI

 $T_{\Lambda} = 25^{\circ}C$

| | DADAMETED | TEST FIGURE | TEST | | ULN | 12003AI | | UNIT |
|----------------------|---|-------------|---|-------------------------|---------------------|---------|------|------|
| | PARAMETER | 1EST FIGURE | CONDITIONS | | MIN | TYP | MAX | UNII |
| | | | | I _C = 200 mA | | | 2.4 | |
| V _{I(on)} | ON-state input voltage | Figure 7-6 | V _{CE} = 2 V | I _C = 250 mA | | | 2.7 | V |
| | | | | I _C = 300 mA | | | 3 | 1 |
| V _{OH} | High-level output voltage after switching | Figure 7-10 | V _S = 50 V, I _O = | 300 mA | V _S - 50 | | | mV |
| | | | I _I = 250 μA, | I _C = 100 mA | | 0.9 | 1.1 | |
| V _{CE(sat)} | Collector-emitter saturation voltage | Figure 7-5 | I _I = 350 μA, | I _C = 200 mA | | 1 | 1.3 | V |
| | | | I _I = 500 μA, | I _C = 350 mA | | 1.2 | 1.6 | |
| I _{CEX} | Collector cutoff current | Figure 7-1 | V _{CE} = 50 V, | I _I = 0 | | | 50 | μA |
| V _F | Clamp forward voltage | Figure 7-8 | I _F = 350 mA | | | 1.7 | 2 | V |
| I _{I(off)} | OFF-state input current | Figure 7-3 | V _{CE} = 50 V, | I _C = 500 μA | 50 | 65 | | μA |
| Iį | Input current | Figure 7-4 | V _I = 3.85 V | | | 0.93 | 1.35 | mA |
| I _R | Clamp reverse current | Figure 7-7 | V _R = 50 V | | | | 50 | μΑ |
| C _i | Input capacitance | | $V_1 = 0,$ | f = 1 MHz | | 15 | 25 | pF |

6.8 Electrical Characteristics: ULN2003AI

 $T_{\Delta} = -40^{\circ}\text{C} \text{ to } 105^{\circ}\text{C}$

| | DADAMETED | TEST FIGURE | TEST CONDITIONS | | ULN | UNIT | | |
|----------------------|---|-------------|---|-------------------------|---------------------|------|------|------|
| | PARAMETER | 1EST FIGURE | IESIC | TEST CONDITIONS | | TYP | MAX | UNII |
| | | | | I _C = 200 mA | | | 2.7 | |
| $V_{I(on)}$ | ON-state input voltage | Figure 7-6 | V _{CE} = 2 V | I _C = 250 mA | | | 2.9 | V |
| | | | | I _C = 300 mA | | | 3 | |
| V _{OH} | High-level output voltage after switching | Figure 7-10 | V _S = 50 V, I _O = | = 300 mA | V _S - 50 | | | mV |
| | | | I _I = 250 μA, | I _C = 100 mA | | 0.9 | 1.2 | |
| V _{CE(sat)} | Collector-emitter saturation voltage | Figure 7-5 | I _I = 350 μA, | I _C = 200 mA | | 1 | 1.4 | V |
| | | | I _I = 500 μA, | I _C = 350 mA | | 1.2 | 1.7 | |
| I _{CEX} | Collector cutoff current | Figure 7-1 | V _{CE} = 50 V, | I _I = 0 | | | 100 | μA |
| V_{F} | Clamp forward voltage | Figure 7-8 | I _F = 350 mA | | | 1.7 | 2.2 | V |
| I _{I(off)} | OFF-state input current | Figure 7-3 | V _{CE} = 50 V, | I _C = 500 μA | 30 | 65 | | μA |
| II | Input current | Figure 7-4 | V _I = 3.85 V | | | 0.93 | 1.35 | mA |
| I _R | Clamp reverse current | Figure 7-7 | V _R = 50 V | | | | 100 | μA |
| Ci | Input capacitance | | V _I = 0, | f = 1 MHz | | 15 | 25 | pF |



6.9 Electrical Characteristics: ULQ2003A and ULQ2004A

over recommended operating conditions (unless otherwise noted)

| | PARAMETER | TEST | TEST CO | ONDITIONS | ULQ | 2003A | | ULQ | 2004A | | UNIT |
|---------------------------------------|---|-------------|---|-------------------------|---------------------|-------|------|---------------------|-------|--|-------|
| | PARAMETER | FIGURE | IESI CC | ONDITIONS | MIN | TYP | MAX | MIN | TYP | MAX | UNIT |
| | | | | I _C = 125 mA | | | | | | 5 | |
| | | | | I _C = 200 mA | | | 2.7 | | | MAX 5 6 6 7 7 8 8 1.1 1.3 1.6 50 100 500 2 0.5 1.45 50 | |
| \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ | ON-state input | Figure 7.6 | \/ - 2\/ | I _C = 250 mA | | | 2.9 | | | | v |
| V _{I(on)} | voltage | Figure 7-6 | V _{CE} – ∠ V | I _C = 275 mA | | | | | | 7 | \ \ \ |
| | | | | I _C = 300 mA | | | 3 | | | | |
| | | | | I _C = 350 mA | | | | | | 8 | |
| V _{OH} | High-level output voltage after switching | Figure 7-10 | V _S = 50 V, I _O | = 300 mA | V _S - 50 | | | V _S - 50 | | | mV |
| | | | I _I = 250 μA, | I _C = 100 mA | | 0.9 | 1.2 | | 0.9 | 1.1 | |
| V _{CE(sat)} | Collector-emitter saturation voltage | Figure 7-5 | I _I = 350 μA, | I _C = 200 mA | | 1 | 1.4 | | 1 | 1.3 | V |
| | cataraner renage | | I _I = 500 μA, | I _C = 350 mA | | 1.2 | 1.7 | | 1.2 | 1.6 | |
| | 0 " | Figure 7-1 | V _{CE} = 50 V, | I ₁ = 0 | | | 100 | | | 50 | |
| I _{CEX} | Collector cutoff current | Figure 7-2 | V _{CE} = 50 V, | I ₁ = 0 | | | | | | 100 | μA |
| | | riguie 7-2 | T _A = 70°C | V _I = 6 V | | | | | | 500 | |
| V _F | Clamp forward voltage | Figure 7-8 | I _F = 350 mA | | | 1.7 | 2.3 | | 1.7 | 2 | V |
| I _{I(off)} | OFF-state input current | Figure 7-3 | V _{CE} = 50 V, T _A = 70°C, | I _C = 500 μA | | 65 | | 50 | 65 | | μΑ |
| | | | V _I = 3.85 V | | | 0.93 | 1.35 | | | | |
| I _I | Input current | Figure 7-4 | V _I = 5 V | | | | | | 0.35 | 0.5 | mA |
| | | | V _I = 12 V | | | | | | 1 | 1.45 | |
| | Clamp reverse | Figure 7.7 | V _R = 50 V | T _A = 25°C | | | 100 | | | 50 | |
| I _R | current | Figure 7-7 | V _R = 50 V | | | | 100 | | | 100 | μA |
| C _i | Input capacitance | | V _I = 0, | f = 1 MHz | | 15 | 25 | | 15 | 25 | pF |

6.10 Switching Characteristics: ULN2002A, ULN2003A, ULN2004A

 $T_A = 25^{\circ}C$

| | PARAMETER | TEST CONDITIONS | ULN2002A ULN | A, ULN2(N2004A | 003A, | UNIT |
|------------------|---|-----------------|-----------------|--------------------|-------|------|
| | | | MIN | TYP | MAX | |
| t _{PLH} | Propagation delay time, low- to high-level output | See Figure 7-9 | | 0.25 | 1 | μs |
| t _{PHL} | Propagation delay time, high- to low-level output | See Figure 7-9 | | 0.25 | 1 | μs |

6.11 Switching Characteristics: ULN2003AI

 $T_A = 25^{\circ}C$

| | PARAMETER | TEST CONDITIONS | ULN | 0.25 1 | | |
|------------------|---|-----------------|-----|--------|-----|------|
| | FARAIVIETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
| t _{PLH} | Propagation delay time, low- to high-level output | See Figure 7-9 | | 0.25 | 1 | μs |
| t _{PHL} | Propagation delay time, high- to low-level output | See Figure 7-9 | | 0.25 | 1 | μs |



6.12 Switching Characteristics: ULN2003AI

 $T_A = -40$ °C to 105°C

| | PARAMETER | TEST CONDITIONS | UL | ULN2003AI MIN TYP MAX 1 10 | | | |
|------------------|---|-----------------|-----|--|-----|------|--|
| | FARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT | |
| t _{PLH} | Propagation delay time, low- to high-level output | See Figure 7-9 | | 1 | 10 | μs | |
| t _{PHL} | Propagation delay time, high- to low-level output | See Figure 7-9 | | 1 | 10 | μs | |

6.13 Switching Characteristics: ULQ2003A, ULQ2004A

over recommended operating conditions (unless otherwise noted)

| | PARAMETER | TEST CONDITIONS | ULQ2003/ | A, ULQ2 | 004A | UNIT |
|------------------|---|-----------------|----------|---------|------|------|
| | PARAIVIETER | TEST CONDITIONS | MIN | TYP | MAX | ONII |
| t _{PLH} | Propagation delay time, low- to high-level output | See Figure 7-9 | | 1 | 10 | μs |
| t _{PHL} | Propagation delay time, high- to low-level output | See Figure 7-9 | | 1 | 10 | μs |

6.14 Typical Characteristics

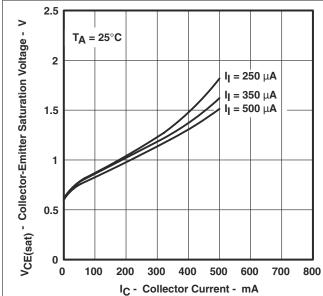


Figure 6-1. Collector-Emitter Saturation Voltage vs Collector Current (One Darlington)

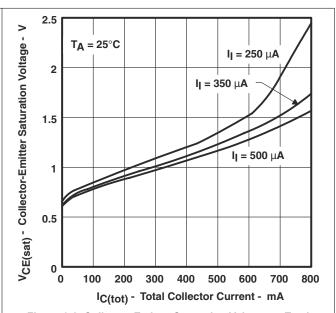


Figure 6-2. Collector-Emitter Saturation Voltage vs Total Collector Current (Two Darlingtons in Parallel)



6.14 Typical Characteristics (continued)

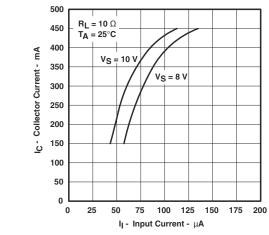


Figure 6-3. Collector Current vs Input Current

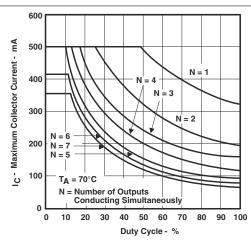


Figure 6-4. D Package Maximum Collector Current vs Duty Cycle

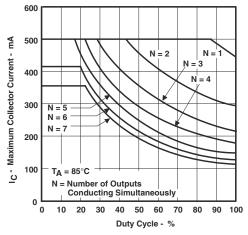


Figure 6-5. N Package Maximum Collector Current vs Duty Cycle

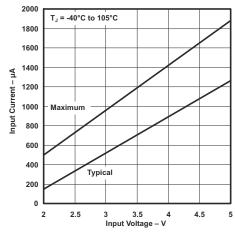


Figure 6-6. Maximum and Typical Input Current vs Input Voltage

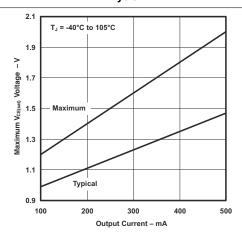


Figure 6-7. Maximum and Typical Saturated V_{CE} vs Output Current

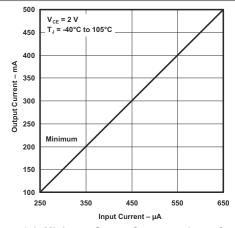


Figure 6-8. Minimum Output Current vs Input Current



7 Parameter Measurement Information

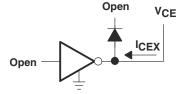


Figure 7-1. I_{CEX} Test Circuit

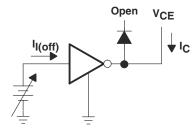
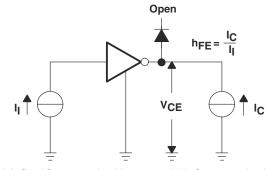


Figure 7-3. I_{I(off)} Test Circuit



 I_{I} is fixed for measuring $V_{\text{CE(sat)}}$, variable for measuring h_{FE} .

Figure 7-5. h_{FE}, V_{CE(sat)} Test Circuit

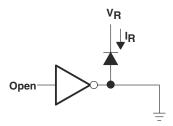


Figure 7-7. I_R Test Circuit

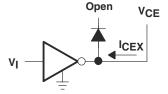


Figure 7-2. I_{CEX} Test Circuit

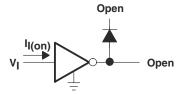


Figure 7-4. I_I Test Circuit

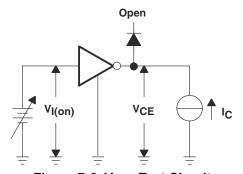


Figure 7-6. V_{I(on)} Test Circuit

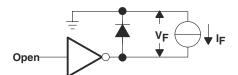


Figure 7-8. V_F Test Circuit

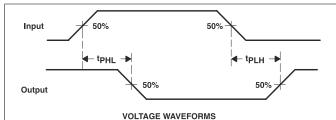
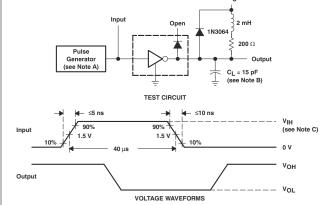


Figure 7-9. Propagation Delay-Time Waveforms



The pulse generator has the following characteristics: PRR = 12.5 kHz, Z_{O} = 50 $\Omega.$

C_L includes probe and jig capacitance.

For testing the ULN2003A device, ULN2003Al device, and ULQ2003A devices, V_{IH} = 3 V; for the ULN2002A device, V_{IH} = 13 V; for the ULN2004A and the ULQ2004A devices, V_{IH} = 8 V.

Figure 7-10. Latch-Up Test Circuit and Voltage Waveforms



8 Detailed Description

8.1 Overview

This standard device has proven ubiquity and versatility across a wide range of applications. This is due to integration of 7 Darlington transistors of the device that are capable of sinking up to 500 mA and wide GPIO range capability.

The ULN2003A device comprises seven high-voltage, high-current NPN Darlington transistor pairs. All units feature a common emitter and open collector outputs. To maximize their effectiveness, these units contain suppression diodes for inductive loads. The ULN2003A device has a series base resistor to each Darlington pair, thus allowing operation directly with TTL or CMOS operating at supply voltages of 5 V or 3.3 V. The ULN2003A device offers solutions to a great many interface needs, including solenoids, relays, lamps, small motors, and LEDs. Applications requiring sink currents beyond the capability of a single output may be accommodated by paralleling the outputs.

This device can operate over a wide temperature range (-40°C to 105°C).

8.2 Functional Block Diagrams

All resistor values shown are nominal. The collector-emitter diode is a parasitic structure and should not be used to conduct current. If the collectors go below GND, an external Schottky diode should be added to clamp negative undershoots.

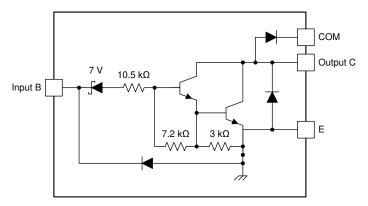


Figure 8-1. ULN2002A Block Diagram

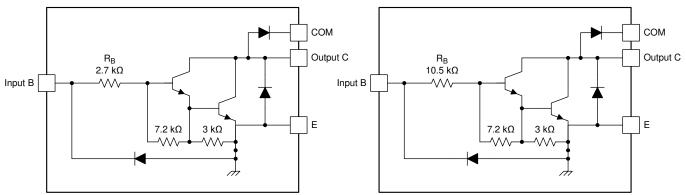


Figure 8-2. ULN2003A, ULQ2003A and ULN2003Al Figure 8-3. ULN2004A and LQ2004A Block Diagram Block Diagram



8.3 Feature Description

Each channel of the ULN2003A device consists of Darlington connected NPN transistors. This connection creates the effect of a single transistor with a very high-current gain (β 2). This can be as high as 10,000 A/A at certain currents. The very high β allows for high-output current drive with a very low input current, essentially equating to operation with low GPIO voltages.

The GPIO voltage is converted to base current through the 2.7-k Ω resistor connected between the input and base of the predriver Darlington NPN. The 7.2-k Ω and 3-k Ω resistors connected between the base and emitter of each respective NPN act as pulldowns and suppress the amount of leakage that may occur from the input.

The diodes connected between the output and COM pin is used to suppress the kick-back voltage from an inductive load that is excited when the NPN drivers are turned off (stop sinking) and the stored energy in the coils causes a reverse current to flow into the coil supply through the kick-back diode.

In normal operation the diodes on base and collector pins to emitter will be reversed biased. If these diodes are forward biased, internal parasitic NPN transistors will draw (a nearly equal) current from other (nearby) device pins.

8.4 Device Functional Modes

8.4.1 Inductive Load Drive

When the COM pin is tied to the coil supply voltage, ULN2003A device is able to drive inductive loads and suppress the kick-back voltage through the internal free-wheeling diodes.

8.4.2 Resistive Load Drive

When driving a resistive load, a pullup resistor is needed in order for ULN2003A device to sink current and for there to be a logic high level. The COM pin can be left floating for these applications.

9 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

9.1 Application Information

Typically, the ULN2003A device drives a high-voltage or high-current (or both) peripheral from an MCU or logic device that cannot tolerate these conditions. This design is a common application of ULN2003A device, driving inductive loads. This includes motors, solenoids and relays. Figure 9-1 shows a model for each load type.

9.2 Typical Application

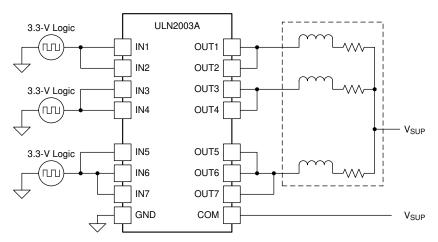


Figure 9-1. ULN2003A Device as Inductive Load Driver

9.2.1 Design Requirements

For this design example, use the parameters listed in Table 9-1 as the input parameters.

DESIGN PARAMETER

GPIO voltage

3.3 V or 5 V

Coil supply voltage

12 V to 48 V

Number of channels

7

Output current (R_{COIL})

Duty cycle

EXAMPLE VALUE

3.3 V or 5 V

12 V to 48 V

7

20 mA to 300 mA per channel

Table 9-1. Design Parameters



9.2.2 Detailed Design Procedure

When using ULN2003A device in a coil driving application, determine the following:

- Input voltage range
- · Temperature range
- · Output and drive current
- Power dissipation

9.2.2.1 Drive Current

The coil voltage (V_{SUP}) , coil resistance (R_{COIL}) , and low-level output voltage $(V_{CE(SAT)} \text{ or } V_{OL})$ determine the coil current

$$I_{COIL} = (V_{SUP} - V_{CE(SAT)}) / R_{COIL}$$
 (1)

9.2.2.2 Low-Level Output Voltage

The low-level output voltage (V_{OL}) is the same as $V_{CE(SAT)}$ and can be determined by, Figure 6-1, Figure 6-2, or Figure 6-7.

9.2.2.3 Power Dissipation and Temperature

The number of coils driven is dependent on the coil current and on-chip power dissipation. The number of coils driven can be determined by Figure 6-4 or Figure 6-5.

For a more accurate determination of number of coils possible, use the below equation to calculate ULN2003A device on-chip power dissipation P_D :

$$P_{D} = \sum_{i=1}^{N} V_{OLi} \times I_{Li}$$
(2)

where

- · N is the number of channels active together
- V_{OLi} is the OUT_i pin voltage for the load current I_{Li}. This is the same as V_{CE(SAT)}

To ensure reliability of ULN2003A device and the system, the on-chip power dissipation must be lower that or equal to the maximum allowable power dissipation ($PD_{(MAX)}$) dictated by below equation Equation 3.

$$PD_{(MAX)} = \frac{\left(T_{J(MAX)} - T_{A}\right)}{\theta_{JA}}$$
(3)

where

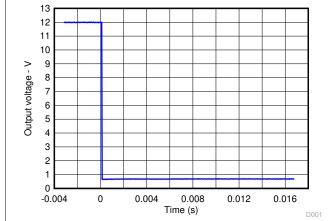
- T_{J(max)} is the target maximum junction temperature
- T_A is the operating ambient temperature
- R_{θJA} is the package junction to ambient thermal resistance

Limit the die junction temperature of the ULN2003A device to less than 125°C. The IC junction temperature is directly proportional to the on-chip power dissipation.



9.2.3 Application Curves

The characterization data shown in Figure 9-2 and Figure 9-3 were generated using the ULN2003A device driving an OMRON G5NB relay and under the following conditions: V_{IN} = 5 V, V_{SUP} = 12 V, and R_{COIL} = 2.8 k Ω .



14
12
> 10
- 0.004
0 0.004 0.008 0.012 0.016
Time (s)

Figure 9-2. Output Response With Activation of Coil (Turnon)

Figure 9-3. Output Response With De-activation of Coil (Turnoff)



9.3 System Examples

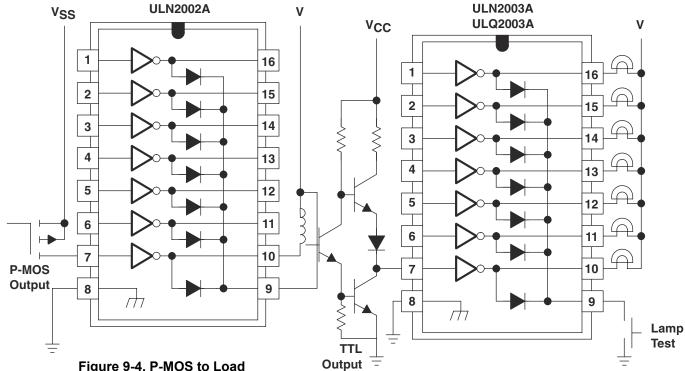


Figure 9-4. P-MOS to Load

Figure 9-5. TTL to Load

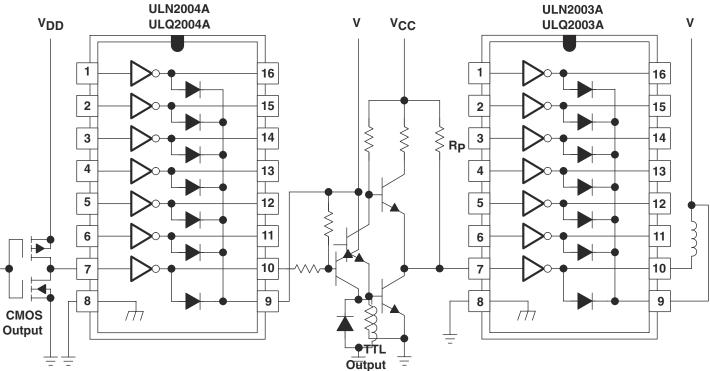


Figure 9-6. Buffer for Higher Current Loads

Figure 9-7. Use of Pullup Resistors to Increase **Drive Current**



10 Power Supply Recommendations

This device does not need a power supply. However, the COM pin is typically tied to the system power supply. When this is the case, it is very important to ensure that the output voltage does not heavily exceed the COM pin voltage. This discrepancy heavily forward biases the fly-back diodes and causes a large current to flow into COM, potentially damaging the on-chip metal or over-heating the device.

11 Layout

11.1 Layout Guidelines

Thin traces can be used on the input due to the low-current logic that is typically used to drive ULN2003A device. Take care to separate the input channels as much as possible, as to eliminate crosstalk. TI recommends thick traces for the output to drive whatever high currents that may be needed. Wire thickness can be determined by the current density of the trace material and desired drive current.

Because all of the channels currents return to a common emitter, it is best to size that trace width to be very wide. Some applications require up to 2.5 A.

11.2 Layout Example

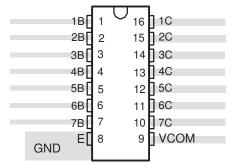


Figure 11-1. Package Layout



12 Device and Documentation Support

12.1 Documentation Support

12.1.1 Related Documentation

For related documentation, see the following:

SN7546x Darlington Transistor Arrays, SLRS023

12.2 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

Table 12-1. Related Links

| PARTS | PRODUCT FOLDER | SAMPLE & BUY | TECHNICAL DOCUMENTS | TOOLS & SOFTWARE | SUPPORT & COMMUNITY |
|-----------|----------------|--------------|---------------------|---------------------|---------------------|
| ULN2002A | Click here | Click here | Click here | Click here | Click here |
| ULN2003A | Click here | Click here | Click here | Click here | Click here |
| ULN2003AI | Click here | Click here | Click here | Click here | Click here |
| ULN2004A | Click here | Click here | Click here | Click here | Click here |
| ULQ2003A | Click here | Click here | Click here | Click here | Click here |
| ULQ2004A | Click here | Click here | Click here | Click here | Click here |

12.3 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

12.4 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

12.5 Trademarks

TI E2E[™] is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

12.6 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

12.7 Glossary

TI Glossary This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical packaging and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser based versions of this data sheet, refer to the left hand navigation.





www.ti.com 8-Jul-2022

PACKAGING INFORMATION

| Orderable Device | Status | Package Type | Package Drawing | Pins | Package Qty | Eco Plan | Lead finish/ Ball material | MSL Peak Temp | Op Temp (°C) | Device Marking (4/5) | Samples |
|------------------|--------|--------------|--------------------|------|----------------|--------------|-------------------------------|--------------------|--------------|----------------------|---------|
| ULN2002AN | ACTIVE | PDIP | N | 16 | 25 | RoHS & Green | NIPDAU | N / A for Pkg Type | -20 to 70 | ULN2002AN | Samples |
| ULN2002ANE4 | ACTIVE | PDIP | N | 16 | 25 | RoHS & Green | NIPDAU | N / A for Pkg Type | -20 to 70 | ULN2002AN | Samples |
| ULN2003AD | ACTIVE | SOIC | D | 16 | 40 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 70 | ULN2003A | Samples |
| ULN2003ADE4 | ACTIVE | SOIC | D | 16 | 40 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 70 | ULN2003A | Samples |
| ULN2003ADR | ACTIVE | SOIC | D | 16 | 2500 | RoHS & Green | NIPDAU SN | Level-1-260C-UNLIM | -40 to 70 | ULN2003A | Samples |
| ULN2003ADRE4 | ACTIVE | SOIC | D | 16 | 2500 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 70 | ULN2003A | Samples |
| ULN2003ADRG3 | ACTIVE | SOIC | D | 16 | 2500 | RoHS & Green | SN | Level-1-260C-UNLIM | -40 to 70 | ULN2003A | Samples |
| ULN2003ADRG4 | ACTIVE | SOIC | D | 16 | 2500 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 70 | ULN2003A | Samples |
| ULN2003AID | ACTIVE | SOIC | D | 16 | 40 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 105 | ULN2003AI | Samples |
| ULN2003AIDE4 | ACTIVE | SOIC | D | 16 | 40 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 105 | ULN2003AI | Samples |
| ULN2003AIDG4 | ACTIVE | SOIC | D | 16 | 40 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 105 | ULN2003AI | Samples |
| ULN2003AIDR | ACTIVE | SOIC | D | 16 | 2500 | RoHS & Green | NIPDAU SN | Level-1-260C-UNLIM | -40 to 105 | ULN2003AI | Samples |
| ULN2003AIDRE4 | ACTIVE | SOIC | D | 16 | 2500 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 105 | ULN2003AI | Samples |
| ULN2003AIDRG4 | ACTIVE | SOIC | D | 16 | 2500 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 105 | ULN2003AI | Samples |
| ULN2003AIN | ACTIVE | PDIP | N | 16 | 25 | RoHS & Green | NIPDAU SN | N / A for Pkg Type | -40 to 105 | ULN2003AIN | Samples |
| ULN2003AINE4 | ACTIVE | PDIP | N | 16 | 25 | RoHS & Green | NIPDAU | N / A for Pkg Type | -40 to 105 | ULN2003AIN | Samples |
| ULN2003AINSR | ACTIVE | SO | NS | 16 | 2000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 105 | ULN2003AI | Samples |
| ULN2003AIPW | ACTIVE | TSSOP | PW | 16 | 90 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 105 | UN2003AI | Samples |
| ULN2003AIPWR | ACTIVE | TSSOP | PW | 16 | 2000 | RoHS & Green | NIPDAU SN | Level-1-260C-UNLIM | -40 to 105 | UN2003AI | Samples |
| ULN2003AIPWRG4 | ACTIVE | TSSOP | PW | 16 | 2000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 105 | UN2003AI | Samples |





8-Jul-2022 www.ti.com

| Orderable Device | Status (1) | Package Type | Package Drawing | Pins | Package Qty | Eco Plan | Lead finish/ Ball material | MSL Peak Temp | Op Temp (°C) | Device Marking (4/5) | Samples |
|------------------|------------|--------------|--------------------|------|----------------|--------------|-------------------------------|--------------------|--------------|-------------------------|---------|
| ULN2003AN | ACTIVE | PDIP | N | 16 | 25 | RoHS & Green | NIPDAU SN | N / A for Pkg Type | -40 to 70 | ULN2003AN | Samples |
| ULN2003ANE4 | ACTIVE | PDIP | N | 16 | 25 | RoHS & Green | NIPDAU | N / A for Pkg Type | -40 to 70 | ULN2003AN | Samples |
| ULN2003ANS | ACTIVE | SO | NS | 16 | 50 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 70 | ULN2003A | Samples |
| ULN2003ANSR | ACTIVE | SO | NS | 16 | 2000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 70 | ULN2003A | Samples |
| ULN2003ANSRE4 | ACTIVE | SO | NS | 16 | 2000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 70 | ULN2003A | Samples |
| ULN2003ANSRG4 | ACTIVE | SO | NS | 16 | 2000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 70 | ULN2003A | Samples |
| ULN2003APW | ACTIVE | TSSOP | PW | 16 | 90 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 70 | UN2003A | Samples |
| ULN2003APWG4 | ACTIVE | TSSOP | PW | 16 | 90 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 70 | UN2003A | Samples |
| ULN2003APWR | ACTIVE | TSSOP | PW | 16 | 2000 | RoHS & Green | NIPDAU SN | Level-1-260C-UNLIM | -40 to 70 | UN2003A | Samples |
| ULN2003APWRG4 | ACTIVE | TSSOP | PW | 16 | 2000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 70 | UN2003A | Samples |
| ULN2004AD | ACTIVE | SOIC | D | 16 | 40 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -20 to 70 | ULN2004A | Samples |
| ULN2004ADE4 | ACTIVE | SOIC | D | 16 | 40 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -20 to 70 | ULN2004A | Samples |
| ULN2004ADG4 | ACTIVE | SOIC | D | 16 | 40 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -20 to 70 | ULN2004A | Samples |
| ULN2004ADR | ACTIVE | SOIC | D | 16 | 2500 | RoHS & Green | NIPDAU SN | Level-1-260C-UNLIM | -20 to 70 | ULN2004A | Samples |
| ULN2004ADRE4 | ACTIVE | SOIC | D | 16 | 2500 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -20 to 70 | ULN2004A | Samples |
| ULN2004ADRG4 | ACTIVE | SOIC | D | 16 | 2500 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -20 to 70 | ULN2004A | Samples |
| ULN2004AN | ACTIVE | PDIP | N | 16 | 25 | RoHS & Green | NIPDAU | N / A for Pkg Type | -20 to 70 | ULN2004AN | Samples |
| ULN2004ANE4 | ACTIVE | PDIP | N | 16 | 25 | RoHS & Green | NIPDAU | N / A for Pkg Type | -20 to 70 | ULN2004AN | Samples |
| ULN2004ANSR | ACTIVE | SO | NS | 16 | 2000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -20 to 70 | ULN2004A | Samples |
| ULQ2003AD | ACTIVE | SOIC | D | 16 | 40 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | ULQ2003A | Samples |
| ULQ2003ADG4 | ACTIVE | SOIC | D | 16 | 40 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | | ULQ2003A | Samples |



PACKAGE OPTION ADDENDUM

www.ti.com 8-Jul-2022

| Orderable Device | Status | Package Type | Package Drawing | | Package Qty | Eco Plan | Lead finish/ Ball material | MSL Peak Temp | Op Temp (°C) | Device Marking (4/5) | Samples |
|------------------|--------|--------------|--------------------|----|----------------|--------------|-------------------------------|--------------------|--------------|-------------------------|---------|
| ULQ2003ADR | ACTIVE | SOIC | D | 16 | 2500 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | ULQ2003A | Samples |
| ULQ2003ADRG4 | ACTIVE | SOIC | D | 16 | 2500 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | | ULQ2003A | Samples |
| ULQ2003AN | ACTIVE | PDIP | N | 16 | 25 | RoHS & Green | NIPDAU | N / A for Pkg Type | -40 to 85 | ULQ2003A | Samples |
| ULQ2004AD | ACTIVE | SOIC | D | 16 | 40 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | ULQ2004A | Samples |
| ULQ2004ADG4 | ACTIVE | SOIC | D | 16 | 40 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | | ULQ2004A | Samples |
| ULQ2004ADR | ACTIVE | SOIC | D | 16 | 2500 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | ULQ2004A | Samples |
| ULQ2004ADRG4 | ACTIVE | SOIC | D | 16 | 2500 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | | ULQ2004A | Samples |
| ULQ2004AN | ACTIVE | PDIP | N | 16 | 25 | RoHS & Green | NIPDAU | N / A for Pkg Type | -40 to 85 | ULQ2004AN | Samples |

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

PACKAGE OPTION ADDENDUM

www.ti.com 8-Jul-2022

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF ULQ2003A, ULQ2004A:

Automotive: ULQ2003A-Q1, ULQ2004A-Q1

NOTE: Qualified Version Definitions:

Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects



www.ti.com 25-Aug-2023

TAPE AND REEL INFORMATION





| A0 | Dimension designed to accommodate the component width |
|----|---|
| В0 | Dimension designed to accommodate the component length |
| K0 | Dimension designed to accommodate the component thickness |
| W | Overall width of the carrier tape |
| P1 | Pitch between successive cavity centers |

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|----------------|-----------------|--------------------|------|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| ULN2003ADR | SOIC | D | 16 | 2500 | 330.0 | 16.4 | 6.5 | 10.3 | 2.1 | 8.0 | 16.0 | Q1 |
| ULN2003ADR | SOIC | D | 16 | 2500 | 330.0 | 16.4 | 6.5 | 10.3 | 2.1 | 8.0 | 16.0 | Q1 |
| ULN2003ADRG3 | SOIC | D | 16 | 2500 | 330.0 | 16.8 | 6.5 | 10.3 | 2.1 | 8.0 | 16.0 | Q1 |
| ULN2003ADRG4 | SOIC | D | 16 | 2500 | 330.0 | 16.4 | 6.5 | 10.3 | 2.1 | 8.0 | 16.0 | Q1 |
| ULN2003ADRG4 | SOIC | D | 16 | 2500 | 330.0 | 16.4 | 6.5 | 10.3 | 2.1 | 8.0 | 16.0 | Q1 |
| ULN2003AIDR | SOIC | D | 16 | 2500 | 330.0 | 16.4 | 6.5 | 10.3 | 2.1 | 8.0 | 16.0 | Q1 |
| ULN2003AIDR | SOIC | D | 16 | 2500 | 330.0 | 16.8 | 6.5 | 10.3 | 2.1 | 8.0 | 16.0 | Q1 |
| ULN2003AIDRG4 | SOIC | D | 16 | 2500 | 330.0 | 16.4 | 6.5 | 10.3 | 2.1 | 8.0 | 16.0 | Q1 |
| ULN2003AINSR | so | NS | 16 | 2000 | 330.0 | 16.4 | 8.2 | 10.5 | 2.5 | 12.0 | 16.0 | Q1 |
| ULN2003AIPWR | TSSOP | PW | 16 | 2000 | 330.0 | 12.4 | 6.9 | 5.6 | 1.6 | 8.0 | 12.0 | Q1 |
| ULN2003AIPWR | TSSOP | PW | 16 | 2000 | 330.0 | 12.4 | 6.9 | 5.6 | 1.6 | 8.0 | 12.0 | Q1 |
| ULN2003AIPWRG4 | TSSOP | PW | 16 | 2000 | 330.0 | 12.4 | 6.9 | 5.6 | 1.6 | 8.0 | 12.0 | Q1 |
| ULN2003ANSR | so | NS | 16 | 2000 | 330.0 | 16.4 | 8.2 | 10.5 | 2.5 | 12.0 | 16.0 | Q1 |
| ULN2003APWR | TSSOP | PW | 16 | 2000 | 330.0 | 12.4 | 6.9 | 5.6 | 1.6 | 8.0 | 12.0 | Q1 |
| ULN2003APWR | TSSOP | PW | 16 | 2000 | 330.0 | 12.4 | 6.9 | 5.6 | 1.6 | 8.0 | 12.0 | Q1 |
| ULN2003APWRG4 | TSSOP | PW | 16 | 2000 | 330.0 | 12.4 | 6.9 | 5.6 | 1.6 | 8.0 | 12.0 | Q1 |



PACKAGE MATERIALS INFORMATION

| Device | Package Type | Package Drawing | | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|--------------|-----------------|--------------------|----|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| ULN2004ADR | SOIC | D | 16 | 2500 | 330.0 | 16.4 | 6.5 | 10.3 | 2.1 | 8.0 | 16.0 | Q1 |
| ULN2004ADR | SOIC | D | 16 | 2500 | 330.0 | 16.4 | 6.5 | 10.3 | 2.1 | 8.0 | 16.0 | Q1 |
| ULN2004ADRG4 | SOIC | D | 16 | 2500 | 330.0 | 16.4 | 6.5 | 10.3 | 2.1 | 8.0 | 16.0 | Q1 |
| ULN2004ADRG4 | SOIC | D | 16 | 2500 | 330.0 | 16.4 | 6.5 | 10.3 | 2.1 | 8.0 | 16.0 | Q1 |
| ULN2004ANSR | so | NS | 16 | 2000 | 330.0 | 16.4 | 8.2 | 10.5 | 2.5 | 12.0 | 16.0 | Q1 |
| ULQ2003ADR | SOIC | D | 16 | 2500 | 330.0 | 16.4 | 6.5 | 10.3 | 2.1 | 8.0 | 16.0 | Q1 |
| ULQ2003ADRG4 | SOIC | D | 16 | 2500 | 330.0 | 16.4 | 6.5 | 10.3 | 2.1 | 8.0 | 16.0 | Q1 |





*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|----------------|--------------|-----------------|------|------|-------------|------------|-------------|
| ULN2003ADR | SOIC | D | 16 | 2500 | 340.5 | 336.1 | 32.0 |
| ULN2003ADR | SOIC | D | 16 | 2500 | 356.0 | 356.0 | 35.0 |
| ULN2003ADRG3 | SOIC | D | 16 | 2500 | 364.0 | 364.0 | 27.0 |
| ULN2003ADRG4 | SOIC | D | 16 | 2500 | 340.5 | 336.1 | 32.0 |
| ULN2003ADRG4 | SOIC | D | 16 | 2500 | 367.0 | 367.0 | 38.0 |
| ULN2003AIDR | SOIC | D | 16 | 2500 | 340.5 | 336.1 | 32.0 |
| ULN2003AIDR | SOIC | D | 16 | 2500 | 364.0 | 364.0 | 27.0 |
| ULN2003AIDRG4 | SOIC | D | 16 | 2500 | 340.5 | 336.1 | 32.0 |
| ULN2003AINSR | so | NS | 16 | 2000 | 356.0 | 356.0 | 35.0 |
| ULN2003AIPWR | TSSOP | PW | 16 | 2000 | 364.0 | 364.0 | 27.0 |
| ULN2003AIPWR | TSSOP | PW | 16 | 2000 | 356.0 | 356.0 | 35.0 |
| ULN2003AIPWRG4 | TSSOP | PW | 16 | 2000 | 356.0 | 356.0 | 35.0 |
| ULN2003ANSR | so | NS | 16 | 2000 | 356.0 | 356.0 | 35.0 |
| ULN2003APWR | TSSOP | PW | 16 | 2000 | 364.0 | 364.0 | 27.0 |
| ULN2003APWR | TSSOP | PW | 16 | 2000 | 356.0 | 356.0 | 35.0 |
| ULN2003APWRG4 | TSSOP | PW | 16 | 2000 | 356.0 | 356.0 | 35.0 |
| ULN2004ADR | SOIC | D | 16 | 2500 | 356.0 | 356.0 | 35.0 |
| ULN2004ADR | SOIC | D | 16 | 2500 | 340.5 | 336.1 | 32.0 |



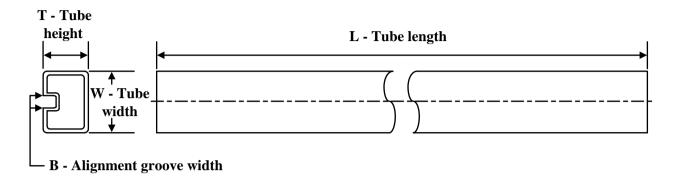
PACKAGE MATERIALS INFORMATION

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|--------------|--------------|-----------------|------|------|-------------|------------|-------------|
| ULN2004ADRG4 | SOIC | D | 16 | 2500 | 356.0 | 356.0 | 35.0 |
| ULN2004ADRG4 | SOIC | D | 16 | 2500 | 340.5 | 336.1 | 32.0 |
| ULN2004ANSR | so | NS | 16 | 2000 | 356.0 | 356.0 | 35.0 |
| ULQ2003ADR | SOIC | D | 16 | 2500 | 340.5 | 336.1 | 32.0 |
| ULQ2003ADRG4 | SOIC | D | 16 | 2500 | 356.0 | 356.0 | 35.0 |



www.ti.com 25-Aug-2023

TUBE



*All dimensions are nominal

| Device | Package Name | Package Type | Pins | SPQ | L (mm) | W (mm) | T (µm) | B (mm) |
|--------------|--------------|--------------|------|-----|--------|--------|--------|--------|
| ULN2002AN | N | PDIP | 16 | 25 | 506 | 13.97 | 11230 | 4.32 |
| ULN2002ANE4 | N | PDIP | 16 | 25 | 506 | 13.97 | 11230 | 4.32 |
| ULN2003AD | D | SOIC | 16 | 40 | 507 | 8 | 3940 | 4.32 |
| ULN2003AD | D | SOIC | 16 | 40 | 506.6 | 8 | 3940 | 4.32 |
| ULN2003ADE4 | D | SOIC | 16 | 40 | 506.6 | 8 | 3940 | 4.32 |
| ULN2003ADE4 | D | SOIC | 16 | 40 | 507 | 8 | 3940 | 4.32 |
| ULN2003AID | D | SOIC | 16 | 40 | 507 | 8 | 3940 | 4.32 |
| ULN2003AIDE4 | D | SOIC | 16 | 40 | 507 | 8 | 3940 | 4.32 |
| ULN2003AIDG4 | D | SOIC | 16 | 40 | 507 | 8 | 3940 | 4.32 |
| ULN2003AIN | N | PDIP | 16 | 25 | 506 | 13.97 | 11230 | 4.32 |
| ULN2003AIN | N | PDIP | 16 | 25 | 506 | 13.97 | 11230 | 4.32 |
| ULN2003AIN | N | PDIP | 16 | 25 | 506.1 | 9 | 600 | 5.4 |
| ULN2003AINE4 | N | PDIP | 16 | 25 | 506 | 13.97 | 11230 | 4.32 |
| ULN2003AINE4 | N | PDIP | 16 | 25 | 506 | 13.97 | 11230 | 4.32 |
| ULN2003AINE4 | N | PDIP | 16 | 25 | 506.1 | 9 | 600 | 5.4 |
| ULN2003AIPW | PW | TSSOP | 16 | 90 | 530 | 10.2 | 3600 | 3.5 |
| ULN2003AN | N | PDIP | 16 | 25 | 506 | 13.97 | 11230 | 4.32 |
| ULN2003AN | N | PDIP | 16 | 25 | 506.1 | 9 | 600 | 5.4 |
| ULN2003AN | N | PDIP | 16 | 25 | 506 | 13.97 | 11230 | 4.32 |
| ULN2003ANE4 | N | PDIP | 16 | 25 | 506 | 13.97 | 11230 | 4.32 |
| ULN2003ANS | NS | SOP | 16 | 50 | 530 | 10.5 | 4000 | 4.1 |
| ULN2003APW | PW | TSSOP | 16 | 90 | 530 | 10.2 | 3600 | 3.5 |
| ULN2003APWG4 | PW | TSSOP | 16 | 90 | 530 | 10.2 | 3600 | 3.5 |
| ULN2004AD | D | SOIC | 16 | 40 | 507 | 8 | 3940 | 4.32 |
| ULN2004AD | D | SOIC | 16 | 40 | 506.6 | 8 | 3940 | 4.32 |
| ULN2004ADE4 | D | SOIC | 16 | 40 | 506.6 | 8 | 3940 | 4.32 |
| ULN2004ADE4 | D | SOIC | 16 | 40 | 507 | 8 | 3940 | 4.32 |
| ULN2004ADG4 | D | SOIC | 16 | 40 | 507 | 8 | 3940 | 4.32 |
| ULN2004ADG4 | D | SOIC | 16 | 40 | 506.6 | 8 | 3940 | 4.32 |



PACKAGE MATERIALS INFORMATION

| Device | Package Name | Package Type | Pins | SPQ | L (mm) | W (mm) | T (µm) | B (mm) |
|-------------|--------------|--------------|------|-----|--------|--------|--------|--------|
| ULN2004AN | N | PDIP | 16 | 25 | 506 | 13.97 | 11230 | 4.32 |
| ULN2004AN | N | PDIP | 16 | 25 | 506 | 13.97 | 11230 | 4.32 |
| ULN2004ANE4 | N | PDIP | 16 | 25 | 506 | 13.97 | 11230 | 4.32 |
| ULN2004ANE4 | N | PDIP | 16 | 25 | 506 | 13.97 | 11230 | 4.32 |
| ULQ2003AD | D | SOIC | 16 | 40 | 507 | 8 | 3940 | 4.32 |
| ULQ2003AD | D | SOIC | 16 | 40 | 506.6 | 8 | 3940 | 4.32 |
| ULQ2003ADG4 | D | SOIC | 16 | 40 | 506.6 | 8 | 3940 | 4.32 |
| ULQ2003ADG4 | D | SOIC | 16 | 40 | 507 | 8 | 3940 | 4.32 |
| ULQ2003AN | N | PDIP | 16 | 25 | 506 | 13.97 | 11230 | 4.32 |
| ULQ2003AN | N | PDIP | 16 | 25 | 506 | 13.97 | 11230 | 4.32 |
| ULQ2004AD | D | SOIC | 16 | 40 | 507 | 8 | 3940 | 4.32 |
| ULQ2004ADG4 | D | SOIC | 16 | 40 | 507 | 8 | 3940 | 4.32 |
| ULQ2004AN | N | PDIP | 16 | 25 | 506 | 13.97 | 11230 | 4.32 |

D (R-PDS0-G16)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.





SMALL OUTLINE PACKAGE



- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.





SOP



- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing
- per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm, per side.



SOF



NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOF



NOTES: (continued)

- 7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.



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